

MoS₂ structures modified by laser irradiation for semiconductor-SERS sensing

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Molybdenum disulfide (MoS₂) is a typical 2D-material attracting in the last years great interest for photocatalysis, optoelectronic and sensing applications. In the field of the chemical sensing, semiconductor surface-enhanced Raman scattering (SERS) has attracted more and more attention due to the possibility to overcome some deficiencies of noble metal nanostructures. A key goal in the employ of semiconductors like 2D-MoS₂ for SERS, is the improvement of the chemical mechanism (CM) of enhancement, mainly based on charge transfer phenomena. Recent progresses in the sensitivity were reported for defective MoS₂ nanosheets and for complex architectures, like MoS₂-nanoflowers [1, 2]. However, MoS₂ layers can easily suffer from aggregation phenomena that negatively influence the CM of enhancement. In this respect, hierarchical MoS₂-based nanostructures provide a hopeful approach to overcome the problem of the self-aggregation, as they are characterized by more stable structures with high chemical sensitivity. Here, MoS₂ nanosheets were properly modified by laser beam irradiation in aqueous dispersion. This is an easy, green and contaminant-free approach able to induce significant structural modifications. Highly defective MoS₂ layers and hierarchical architectures, like flower, tube and assembled lamellar structures, were obtained by a Nd:YAG nanosecond pulsed laser and were chemically characterised by XPS, UV and PL spectroscopies. The morphology of samples was assessed by scanning transmission electron and atomic force microscopy. SERS properties were studied using the 4-mercaptobenzoic acid (4-MBA) as a standard molecule. By using a Micro-Raman spectrometer, it was possible to find quickly isolated hierarchical structures and study the signal enhancement of the surface adsorbed analyte. Different chemical sensitivities were found as a function of the shape and composition and were attributed to different contributions: (a) the formation of a 1T MoS₂ phase, (b) the high surface area of the produced structures and (c) the presence of laser-induced defects. The as-developed strategy may therefore open up interesting perspectives for designing semiconductor materials in the field of SERS sensing.

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References: [1] Ying Yin et al. *Adv. Funct. Mater.* 2017, 27, 1606694; [2] Jaspal Singh et al. *Journal of Alloys and Compounds* 849 (2020) 156502.